

P-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY

V_{DS} (V)	-100
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -10$ V	0.0111
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.0150
Q_g typ. (nC)	125
I_D (A)	-80
Configuration	Single

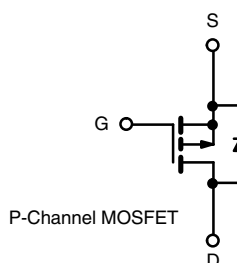
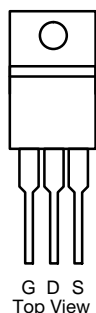
FEATURES

- DT-TrenchPower MOSFET
- Maximum 175 °C junction temperature
- Low $R_{DS(on)}$ minimizes power loss from conduction
- 100 % R_g and UIS tested

APPLICATIONS

- Battery protection
- Motor drive control
- Load switch


RoHS
 COMPLIANT

TO-220AB


ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-100	V
Gate-source voltage	V_{GS}	± 20	
Continuous drain current ^d ($T_J = 175$ °C)	I_D	$T_C = 25$ °C	A
		$T_C = 125$ °C	
Pulsed drain current (100 μ s)	I_{DM}	-240	
Avalanche current	I_{AS}	-75	
Single pulse avalanche energy ^a	E_{AS}	213	mJ
Power dissipation	P_D	$T_C = 25$ °C ^c	W
		$T_C = 125$ °C ^b	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	TYPICAL	UNIT
Junction-to-ambient	R_{thJA}	45	°C/W
Junction-to-case	R_{thJC}	0.3	

Notes

- Duty cycle ≤ 1 %
- When mounted on 1" square PCB (FR4 material)
- See SOA curve for voltage derating
- Limited by package

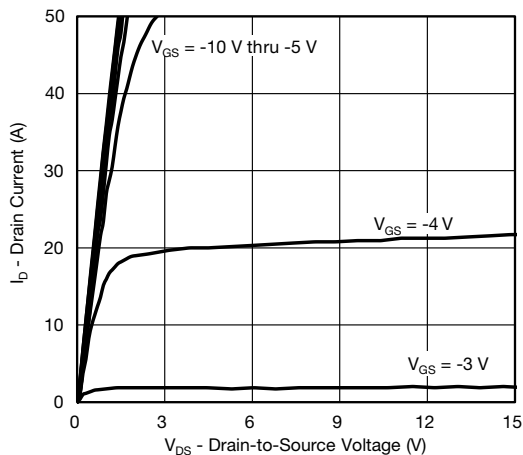
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-100	-	-	V
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.5	-	-2.5	
Gate-body leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -100 V, V _{GS} = 0 V	-	-	-1	μA
		V _{DS} = -80 V, V _{GS} = 0 V, T _J = 125 °C	-	-	-50	
		V _{DS} = -80 V, V _{GS} = 0 V, T _J = 175 °C	-	-	-250	
On-state drain current ^a	I _{D(on)}	V _{DS} ≤ -5 V, V _{GS} = -10 V	-80	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V, I _D = -30 A	-	0.0111	0.0149	Ω
		V _{GS} = -4.5 V, I _D = -20 A	-	0.0150	0.0197	
Forward transconductance ^a	g _{fs}	V _{DS} = -15 V, I _D = -25 A	-	60	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = -50 V, f = 1 MHz	-	14208	-	pF
Output capacitance	C _{oss}		-	3980	-	
Reverse transfer capacitance	C _{rss}		-	253	-	
Total gate charge ^c	Q _g	V _{DS} = -50 V, V _{GS} = -10 V, I _D = -30 A	-	125	190	nC
Gate-source charge ^c	Q _{gs}		-	29	-	
Gate-drain charge ^c	Q _{gd}		-	30	-	
Gate resistance	R _g	f = 1 MHz	1.3	6.5	13	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = -50 V, R _L = 0.71 Ω I _D ≅ -30 A, V _{GEN} = -10 V, R _g = 1 Ω	-	20	30	ns
Rise time ^c	t _r		-	40	60	
Turn-off delay time ^c	t _{d(off)}		-	110	200	
Fall time ^c	t _f		-	40	60	
Drain-Source Body Diode Characteristics (T _C = 25 °C ^b)						
Continuous current	I _S		-	-	-80	A
Pulsed current	I _{SM}		-	-	-240	
Forward voltage ^a	V _{SD}	I _F = -85 A, V _{GS} = 0 V	-	-1	-1.5	V
Reverse recovery time	t _{rr}	I _F = -85 A, dI/dt = 100 A/μs	-	110	170	ns
Peak reverse recovery charge	I _{RM(REC)}		-	-7	-11	A
Reverse recovery charge	Q _{rr}		-	0.38	0.57	μC

Notes

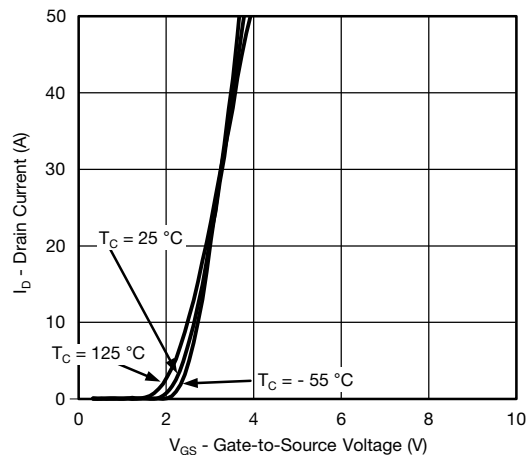
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- Guaranteed by design, not subject to production testing
- Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

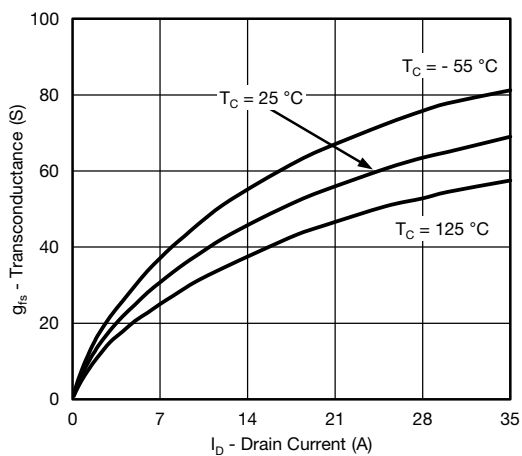
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



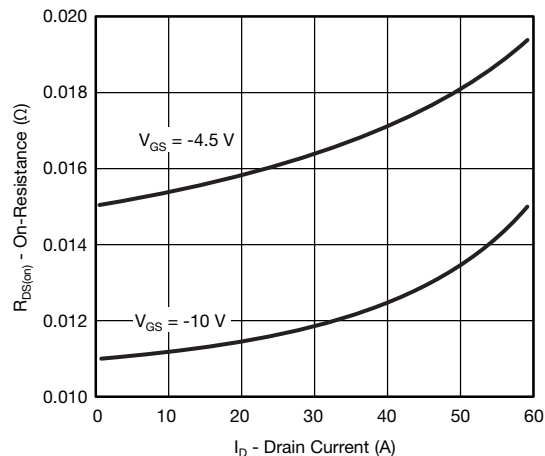
Output Characteristics



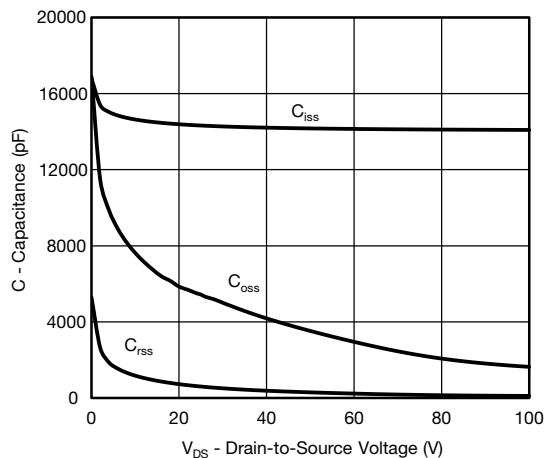
Transfer Characteristics



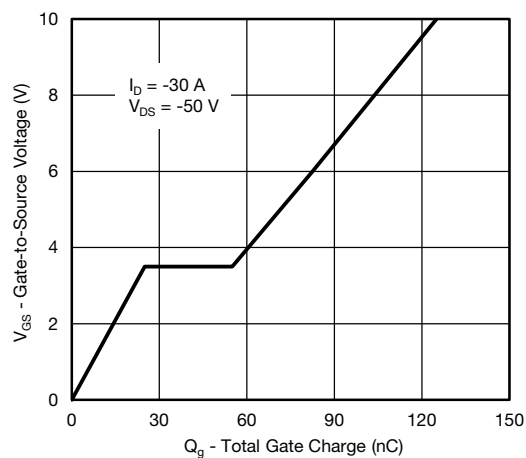
Transconductance



On-Resistance vs. Drain Current

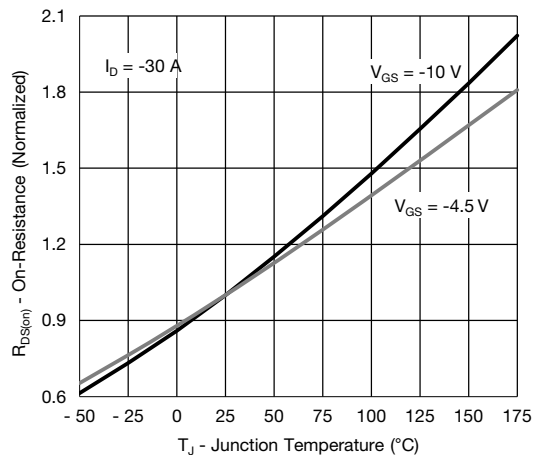


Capacitance

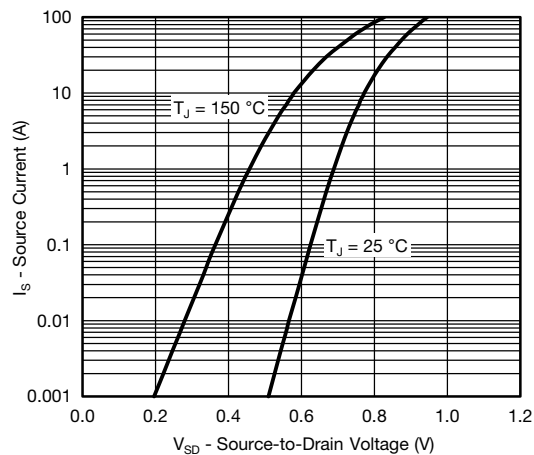


Gate Charge

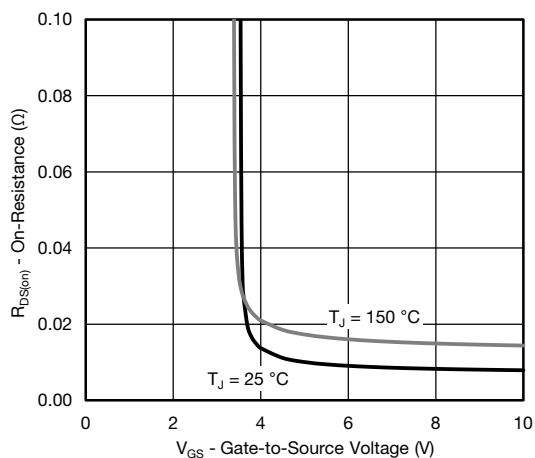
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



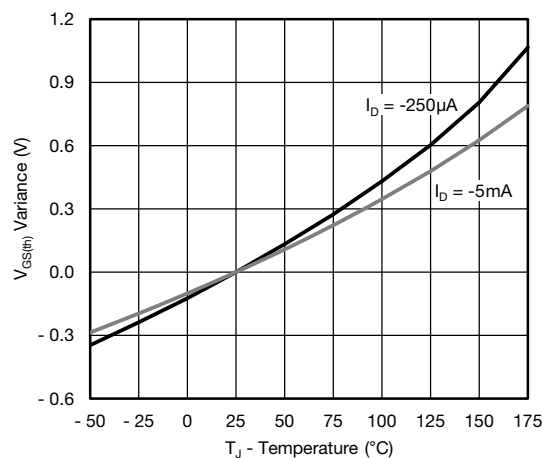
On-Resistance vs. Junction Temperature



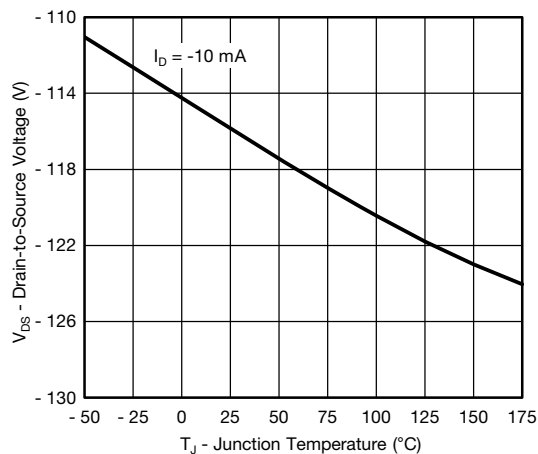
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

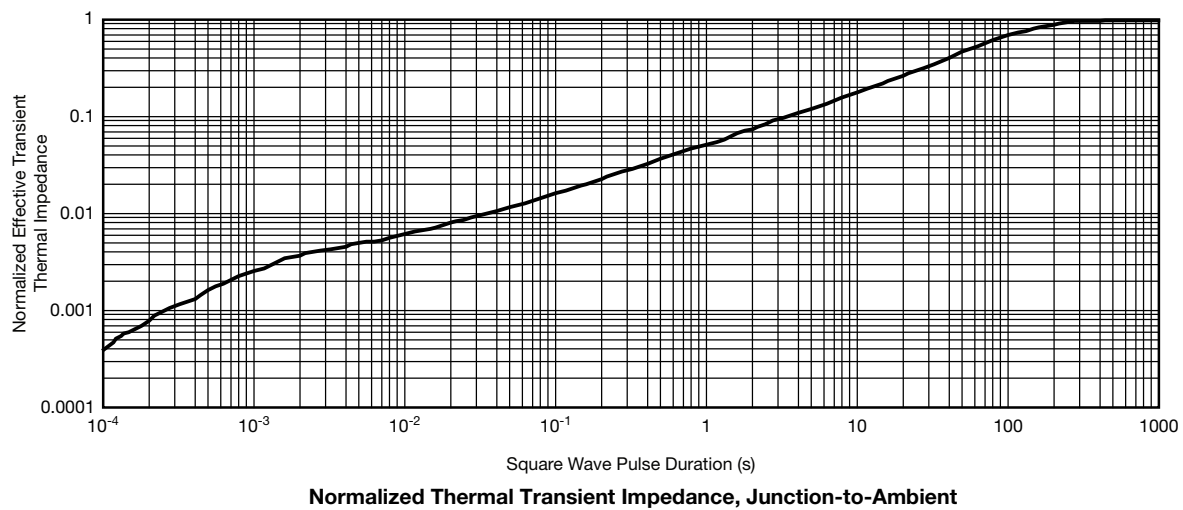
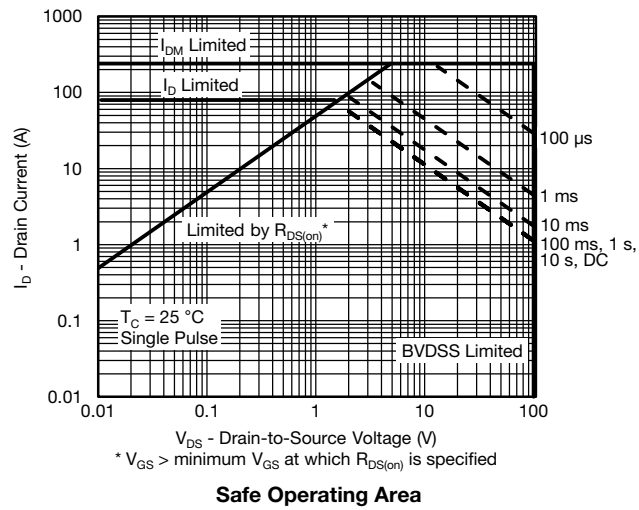


Threshold Voltage

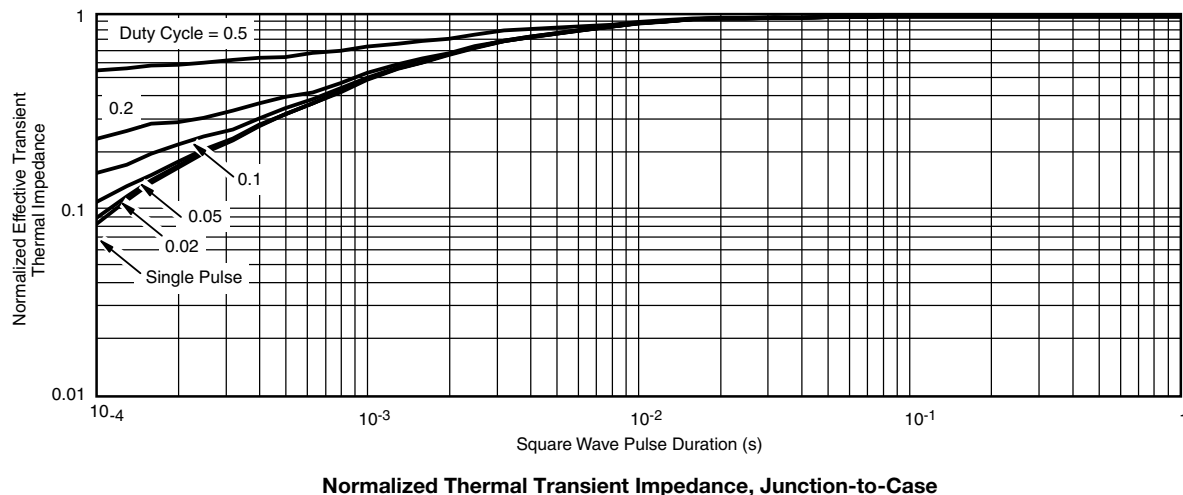


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient ($25\text{ }^{\circ}\text{C}$)
 - Normalized Transient Thermal Impedance Junction to Case ($25\text{ }^{\circ}\text{C}$)
- are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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